NSN 5961-01-376-2083

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-376-2083 **Inclosure Material:** Metal **Overall Length:** 1.865 inches **Overall Height:** Between 0.250 inches and 0.270 inches Overall Width: Between 0.995 inches and 1.005 inches **Mounting Facility Quantity: Component Name And Quantity:** 4 transistor **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 500.0 drain to source voltage all transistor and 40.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 26.00 amperes drain current all transistor **Power Rating Per Characteristic:** 400.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0